# TrenchHV<sup>™</sup> Power MOSFET

## IXTH130N15T IXTQ130N15T

 $V_{DSS} = 150 V \\ I_{D25} = 130 A \\ R_{DS(on)} \le 12 m\Omega$ 

N-Channel Enhancement Mode Avalanche Rated

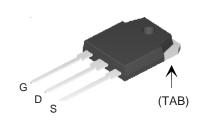


| s        |       | OF    |
|----------|-------|-------|
| <u>-</u> | G D S | (TAB) |

#### **Symbol Test Conditions Maximum Ratings** $\mathbf{V}_{\mathrm{DSS}}$ $T_{1} = 25^{\circ}C \text{ to } 175^{\circ}C$ 150 $\mathbf{V}_{\underline{\mathsf{DGR}}}$ $T_{\perp} = 25^{\circ}\text{C} \text{ to } 175^{\circ}\text{C}; R_{GS} = 1 \text{ M}\Omega$ 150 V Transient ± 30 ٧ V<sub>GSM</sub> $T_{c} = 25^{\circ}C$ 130 I<sub>D25</sub> Lead Current Limit, RMS 75 Α LRMS $T_{\rm C} = 25$ °C, pulse width limited by $T_{\rm JM}$ 330 Α DM $T_{\rm C} = 25^{\circ}{\rm C}$ 5 Α $T_{c}^{r} = 25^{\circ}C$ 1.2 dv/dt $I_{_{\mathrm{S}}} \ \le I_{_{\mathrm{DM}}}, \ \mathrm{di/dt} \le 100 \ \mathrm{A/ms}, \ V_{_{\mathrm{DD}}} \le V_{_{\mathrm{DSS}}}$ 3 V/ns $T_{J} \le 175^{\circ}C, R_{G} = 2.5 \Omega$ $T_{\rm C} = 25^{\circ}C$ $\mathbf{P}_{\mathrm{D}}$ 750 Т<sub>Ј</sub> °C -55 ... +175 °C 175 °C T<sub>stg</sub> -55 ... +175 °C 1.6 mm (0.062 in.) from case for 10 s 300 T, Plastic body for 10 seconds $^{\circ}\text{C}$ 260 M Mounting torque 1.13 / 10 Nm/lb.in. Weight TO-3P 5.5 g TO-247 6

#### TO-3P(IXTQ)

TO-247 (IXTH)



| G = Gate   | D = Drain   |
|------------|-------------|
| S = Source | TAB = Drain |

#### Features

- Unclamped Inductive Switching (UIS) rated
- Low package inductance
- easy to drive and to protect
- 175 °C Operating Temperature

#### **Advantages**

- Easy to mount
- Space savings
- High power density

| Symbol<br>(T <sub>1</sub> = 25°C | Test Conditions unless otherwise specified)               |                        |     | aracteri<br> Typ. | stic Va<br>  Max |           |
|----------------------------------|---|------------------------|-----|-------------------|------------------|-----------|
| BV <sub>DSS</sub>                | $V_{GS} = 0 \text{ V}, I_{D} = 250 \mu\text{A}$           |                        | 150 |                   |                  | V         |
| V <sub>GS(th)</sub>              | $V_{DS} = V_{GS}, I_{D} = 1 \text{ mA}$                   |                        | 2.5 |                   | 4.5              | V         |
| I <sub>gss</sub>                 | $V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$         |                        |     |                   | ± 200            | nA        |
| I <sub>DSS</sub>                 | $V_{DS} = V_{DSS}$<br>$V_{GS} = 0 V$                      | T <sub>J</sub> = 150°C |     |                   | 5<br>250         | μA<br>μA  |
| R <sub>DS(on)</sub>              | $V_{GS} = 10 \text{ V}, I_{D} = 0.5 I_{D25}, \text{ Not}$ | tes 1, 2               |     | 10                | 12               | $m\Omega$ |



| Symbol                | <b>Test Conditions</b>   | Charac | cteristic | Values    |
|-----------------------|--|--------|-----------|-----------|
| $(T_J = 25^{\circ}C)$ | unless otherwise specified)  | Min.   | Тур.      | Max.      |
| $g_{fs}$              | $V_{DS} = 10 \text{ V}; I_{D} = 60 \text{ A}, \text{ Note 1}$                      | 60     | 100       | S         |
| C <sub>iss</sub>      |  |        | 9800      | pF        |
| C <sub>oss</sub>      | $V_{GS} = 0 \text{ V}, V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$                   |        | 1450      | pF        |
| C <sub>rss</sub>      |  |        | 320       | pF        |
| t <sub>d(on)</sub>    | Resistive Switching Times  |        | 23        | ns        |
| t,                    | $V_{GS} = 10 \text{ V}, V_{DS} = 0.5 \text{ V}_{DSS}, I_{D} = 0.5 \text{ I}_{D25}$ |        | 16        | ns        |
| t <sub>d(off)</sub>   | $R_{_G} = 2.5 \Omega \text{ (External)}$   |        | 57        | ns        |
| t <sub>f</sub>        |  |        | 27        | ns        |
| Q <sub>g(on)</sub>    |  |        | 113       | nC        |
| Q <sub>gs</sub>       | $V_{GS} = 10 \text{ V}, V_{DS} = 0.5 V_{DSS}, I_{D} = 0.5 I_{D25}$                 |        | 32        | nC        |
| $Q_{gd}$              |  |        | 31        | nC        |
| R <sub>thJC</sub>     |  |        |           | 0.20 °C/W |
| R <sub>thCS</sub>     |  |        | 0.25      | °C/W      |

#### Source-Drain Diode

| <b>Symbol</b> $T_J = 25^{\circ}C$ ( | Test Conditions unless otherwise specified)                | Ci<br>Min. | haracte<br>Typ. | ristic Va<br>Max. | lues |
|-------------------------------------|--|------------|-----------------|-------------------|------|
| I <sub>s</sub>                      | V <sub>GS</sub> = 0 V                                      |            |                 | 130               | Α    |
| I <sub>SM</sub>                     | Pulse width limited by T <sub>JM</sub>                     |            |                 | 330               | Α    |
| V <sub>SD</sub>                     | $I_F = 50 \text{ A}, V_{GS} = 0 \text{ V}, \text{ Note 1}$ |            |                 | 1.2               | V    |
| t <sub>rr</sub>                     | $I_F = 50 \text{ A}, -di/dt = 100 \text{ A}/\mu\text{s}$   |            | 100             |                   | ns   |
|                                     | $V_R = 25 \text{ V}, V_{GS} = 0 \text{ V}$                 |            |                 |                   |      |

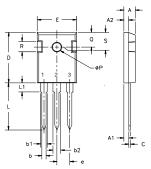
Notes: 1. Pulse test,  $t \le 300$  ms, duty cycle,  $d \le 2$  %;

2. On through-hole packages,  $R_{\rm DS(on)}$  Kelvin test contact location must be 5 mm or less from the package body.

#### **PRELIMINARY TECHNICAL INFORMATION**

The product presented herein is under development. The Technical Specifications offered are derived from data gathered during objective characterizations of preliminary engineering lots; but also may yet contain some information supplied during a preproduction design evaluation. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

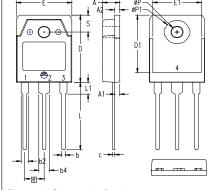
#### **TO-247AD Outline**



Terminals: 1 - Gate 2 - Drain 3 - Source Tab - Drain

| Dim.           | Millimeter |       | Inc   | Inches |  |
|----------------|------------|-------|-------|--------|--|
|                | Min.       | Max.  | Min.  | Max.   |  |
| Α              | 4.7        | 5.3   | .185  | .209   |  |
| A,             | 2.2        | 2.54  | .087  | .102   |  |
| $A_2$          | 2.2        | 2.6   | .059  | .098   |  |
| b              | 1.0        | 1.4   | .040  | .055   |  |
| b <sub>1</sub> | 1.65       | 2.13  | .065  | .084   |  |
| b <sub>2</sub> | 2.87       | 3.12  | .113  | .123   |  |
| С              | .4         | .8    | .016  | .031   |  |
| D              | 20.80      | 21.46 | .819  | .845   |  |
| Е              | 15.75      | 16.26 | .610  | .640   |  |
| е              | 5.20       | 5.72  | 0.205 | 0.225  |  |
| L              | 19.81      | 20.32 | .780  | .800   |  |
| L1             |            | 4.50  |       | .177   |  |
| ÆP             | 3.55       | 3.65  | .140  | .144   |  |
| Q              | 5.89       | 6.40  | 0.232 | 0.252  |  |
| R              | 4.32       | 5.49  | .170  | .216   |  |
| S              | 6.15       | BSC   | 242   | BSC    |  |

### TO-3P (IXTQ) Outline



Pins: 1 - Gate 2 - Drain 3 - Source 4, TAB - Drain

| SYM | INCH | ES   | MILLIN | ETERS |
|-----|------|------|--------|-------|
| SIM | MIN  | MAX  | MIN    | MAX   |
| Α   | .185 | .193 | 4.70   | 4.90  |
| Α1  | .051 | .059 | 1.30   | 1.50  |
| A2  | .057 | .065 | 1.45   | 1.65  |
| b   | .035 | .045 | 0.90   | 1.15  |
| b2  | .075 | .087 | 1.90   | 2.20  |
| b4  | .114 | .126 | 2.90   | 3.20  |
| С   | .022 | .031 | 0.55   | 0.80  |
| D   | .780 | .791 | 19.80  | 20.10 |
| D1  | .665 | .677 | 16.90  | 17.20 |
| E   | .610 | .622 | 15.50  | 15.80 |
| E1  | .531 | .539 | 13.50  | 13.70 |
| е   | .215 | BSC  | 5.45   | BSC   |
| L   | .779 | .795 | 19.80  | 20.20 |
| L1  | .134 | .142 | 3.40   | 3.60  |
| ØΡ  | .126 | .134 | 3.20   | 3.40  |
| øP1 | .272 | .280 | 6.90   | 7.10  |
| S   | .193 | .201 | 4.90   | 5.10  |

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Fig. 1. Output Characteristics @ 25°C

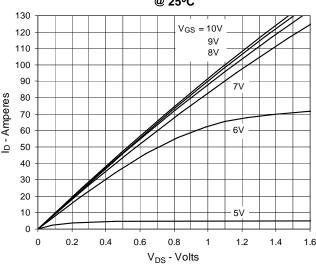


Fig. 2. Extended Output Characteristics @ 25°C

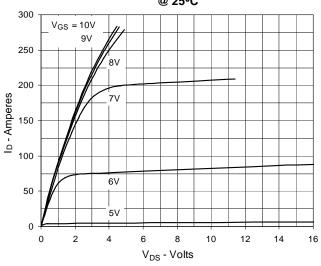


Fig. 3. Output Characteristics

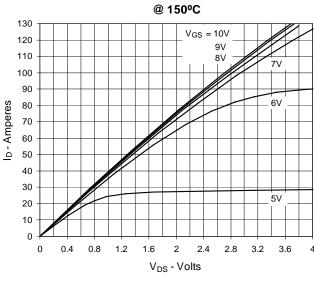


Fig. 4.  $R_{DS(on)}$  Normalized to  $I_D = 65A$  Value vs. Junction Temperature

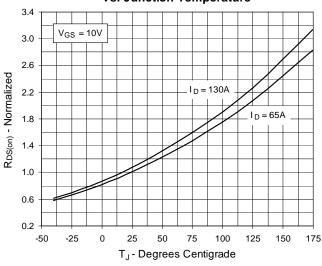


Fig. 5.  $R_{DS(on)}$  Normalized to  $I_D = 65A$  Value vs. Drain Current

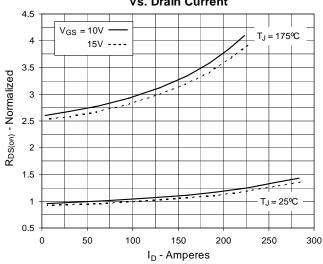
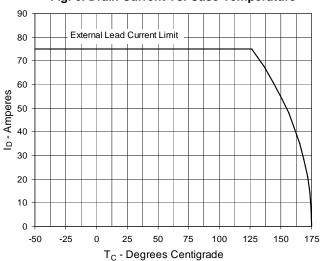
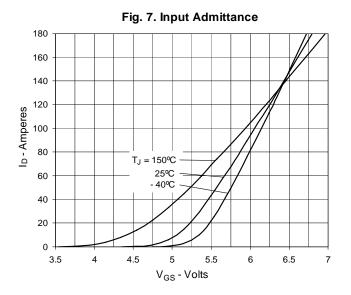
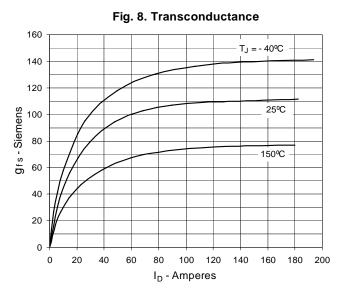


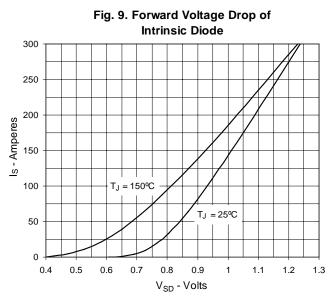
Fig. 6. Drain Current vs. Case Temperature

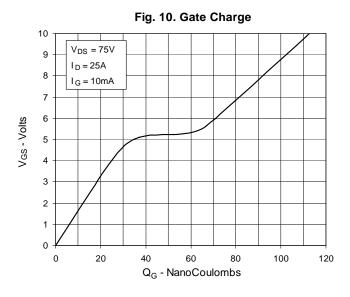


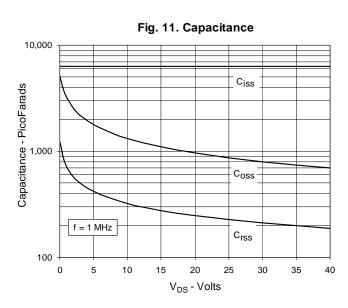


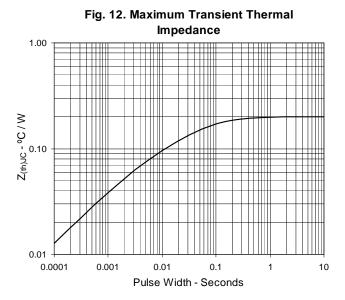












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Fig. 13. Resistive Turn-on Rise Time vs. Junction Temperature

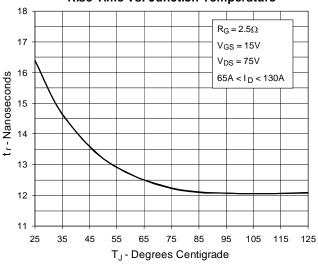


Fig. 15. Resistive Turn-on Switching Times vs. Gate Resistance

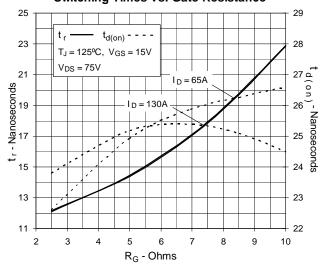


Fig. 17. Resistive Turn-off Switching Times vs. Drain Current

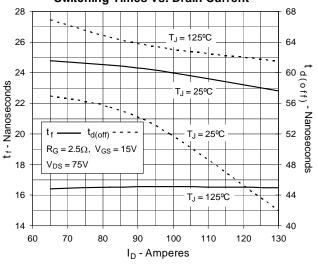


Fig. 14. Resistive Turn-on Rise Time vs. Drain Current

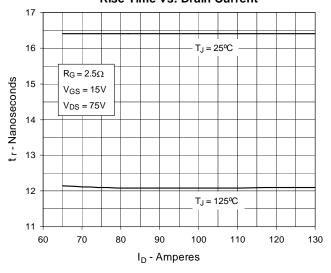


Fig. 16. Resistive Turn-off
Switching Times vs. Junction Temperature

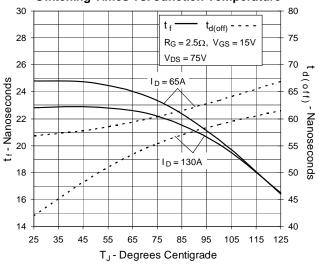


Fig. 18. Resistive Turn-off

